36Mb QDRII SRAM Specification

165 FBGA with Pb & Pb-Free (RoHS compliant)



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Document Title

1Mx36-bit, 2Mx18-bit, 4Mx9-bit QDR™ II b2 SRAM

Revision History

Rev. No.	<u>History</u>	Draft Date	<u>Remark</u>
0.0	1. Initial document.	Jan. 17, 2006	Advance
0.1	1. Put the data in the table of DC Characteristics, Pin Capacitance and Thermal Resistance.	Apr. 26, 2006	Preliminary
0.2	Add 300MHz Bin Change AC Characteristics.	May. 04, 2006	Preliminary
0.3	1. Change Samsung JEDEC Code in ID REGISTER DEFINITION	Jun. 05, 2006	Preliminary
1.0	Final Change Vss/SA to NC/SA in Pin Configuration	Jul. 10, 2006	Final
1.1	1. Correct typo	Aug. 23, 2006	Final



1Mx36-bit, 2Mx18-bit, 4Mx9-bit QDR™ II b2 SRAM

FEATURES

- 1.8V+0.1V/-0.1V Power Supply.
- DLL circuitry for wide output data valid window and future frequency scaling.
- I/O Supply Voltage 1.5V+0.1V/-0.1V for 1.5V I/O, 1.8V+0.1V/-0.1V for 1.8V I/O.
- Separate independent read and write data ports with concurrent read and write operation
- HSTL I/O
- Full data coherency, providing most current data.
- Synchronous pipeline read with self timed early write.
- Registered address, control and data input/output.
- DDR (Double Data Rate) Interface on read and write ports.
- Fixed 2-bit burst for both read and write operation.
- · Clock-stop supports to reduce current.
- Two input clocks (K and K) for accurate DDR timing at clock rising edges only.
- Two input clocks for output data (C and C) to minimize clock-skew and flight-time mismatches.
- Two echo clocks (CQ and CQ) to enhance output data traceability.
- · Single address bus.
- Byte write (x9, x18, x36) function.
- Separate read/write control pin (R and \overline{W})
- Simple depth expansion with no data contention.
- Programmable output impedance.
- JTAG 1149.1 compatible test access port.
- 165FBGA(11x15 ball array FBGA) with body size of 15x17mm
 Lead Free

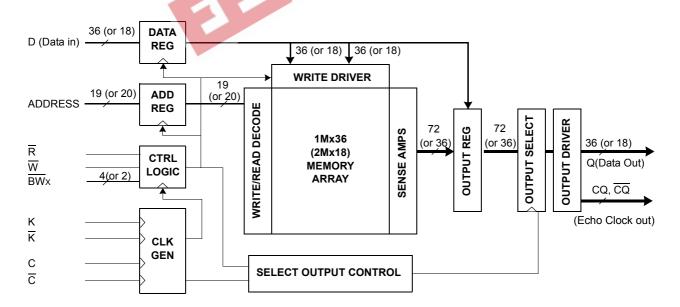
Org.	Part Number	Cycle Time	Access Time	Unit
	K7R323682C-F(E)C(I)30	3.3	0.45	ns
X36	K7R323682C-F(E)C(I)25	4.0	0.45	ns
	K7R323682C-F(E)C(I)20	5.0	0.45	ns
	K7R321882C-F(E)C(I)30	3.3	0.45	ns
X18	K7R321882C-F(E)C(I)25	4.0	0.45	ns
	K7R321882C-F(E)C(I)20	5.0	0.45	ns
	K7R320982C-F(E)C(I)30	3.3	0.45	ns
X9	K7R320982C-F(E)C(I)25	4.0	0.45	ns
	K7R320982C-F(E)C(I)20	5.0	0.45	ns

* -F(E)C(I)

F(E) [Package type]: E-Pb Free, F-Pb

C(I) [Operating Temperature]: C-Commercial, I-Industrial

FUNCTIONAL BLOCK DIAGRAM



 $\textbf{Notes: 1. Numbers in (\) are for x18 device, x9 device also the same with appropriate adjustments of depth and width.}$



PIN CONFIGURATIONS(TOP VIEW) K7R323682C(1Mx36)

	1	2	3	4	5	6	7	8	9	10	11
Α	CQ	NC/SA*	NC/SA*	W	BW ₂	K	BW ₁	R	SA	NC/SA*	CQ
В	Q27	Q18	D18	SA	BW ₃	K	BW ₀	SA	D17	Q17	Q8
С	D27	Q28	D19	Vss	SA	SA	SA	Vss	D16	Q7	D8
D	D28	D20	Q19	Vss	Vss	Vss	Vss	Vss	Q16	D15	D7
E	Q29	D29	Q20	VDDQ	Vss	Vss	Vss	VDDQ	Q15	D6	Q6
F	Q30	Q21	D21	VDDQ	VDD	Vss	VDD	VDDQ	D14	Q14	Q5
G	D30	D22	Q22	VDDQ	VDD	Vss	VDD	VDDQ	Q13	D13	D5
Н	Doff	VREF	VDDQ	VDDQ	VDD	Vss	VDD	VDDQ	VDDQ	VREF	ZQ
J	D31	Q31	D23	VDDQ	VDD	Vss	VDD	VDDQ	D12	Q4	D4
K	Q32	D32	Q23	VDDQ	VDD	Vss	VDD	VDDQ	Q12	D3	Q3
L	Q33	Q24	D24	VDDQ	Vss	Vss	Vss	VDDQ	D11	Q11	Q2
М	D33	Q34	D25	Vss	Vss	Vss	Vss	Vss	D10	Q1	D2
N	D34	D26	Q25	Vss	SA	SA	SA	Vss	Q10	D9	D1
Р	Q35	D35	Q26	SA	SA	С	SA	SA	Q9	D0	Q0
R	TDO	TCK	SA	SA	SA	C	SA	SA	SA	TMS	TDI

Notes: 1. * Checked No Connect (NC) or Vss pins are reserved for higher density address, i.e. 3A for 72Mb, 10A for 144Mb and 2A for 288Mb. 2. BWo controls write to D0:D8, BW1 controls write to D9:D17, BW2 controls write to D18:D26 and BW3 controls write to D27:D35.

PIN NAME

		A 7		
SYMBOL	PIN NUMBERS	20 75	DESCRIPTION	NOTE
K, \overline{K}	6B, 6A	CIL	Input Clock	
C, C	6P, 6R		Input Clock for Output Data	1
CQ, CQ	11A, 1A	1	Output Echo Clock	
Doff	1H)		DLL Disable when low	
SA	9A,4B,8B,5C-7C,5N-7N,4P,5P,7P,8P,3R-5	R,7R-9R	Address Inputs	
D0-35	10P,11N,11M,10K,11J,11G,10E,11D,11C,1 9J,10G,9F,10D,9C,9B,3B,3C,2D,3F,2G,3J, 1C,1D,2E,1G,1J,2K,1M,1N,2P		Data Inputs	
Q0-35	11P,10M,11L,11K,10J,11F,11E,10C,11B,9 9K,9G,10F,9E,9D,10B,2B,3D,3E,2F,3G,3 3P,1B,2C,1E,1F,2J,1K,1L,2M,1F	K,2L,3N	Data Outputs	
W	4A		Write Control Pin, active when low	
R	8A		Read Control Pin, active when low	
BW0, BW1,BW2, BW3	7B,7A,5A,5B		Block Write Control Pin, active when low	
VREF	2H,10H		Input Reference Voltage	
ZQ	11H		Output Driver Impedance Control Input	2
VDD	5F,7F,5G,7G,5H,7H,5J,7J,5K,7K		Power Supply (1.8 V)	
VDDQ	4E,8E,4F,8F,4G,8G,3H,4H,8H,9H,4J,8J,4k	(,8K,4L,8L	Output Power Supply (1.5V or 1.8V)	
Vss	4C,8C,4D-8D,5E-7E,6F,6G,6H,6J,6K,5L-7L,4	M, 8M,4N,8N	Ground	
TMS	10R		JTAG Test Mode Select	
TDI	11R		JTAG Test Data Input	
TCK	2R		JTAG Test Clock	
TDO	1R		JTAG Test Data Output	
NC	2A,3A,10A,		No Connect	3



^{2.} When ZQ pin is directly connected to Vpp output impedance is set to minimum value and it cannot be connected to ground or left unconnected.

3. Not connected to chip pad internally.

PIN CONFIGURATIONS (TOP VIEW) K7R321882C(2Mx18)

	1	2	3	4	5	6	7	8	9	10	11
Α	CQ	NC/SA*	SA	W	BW ₁	K	NC	R	SA	NC/SA*	CQ
В	NC	Q9	D9	SA	NC	K	BW 0	SA	NC	NC	Q8
С	NC	NC	D10	Vss	SA	SA	SA	Vss	NC	Q7	D8
D	NC	D11	Q10	Vss	Vss	Vss	Vss	Vss	NC	NC	D7
E	NC	NC	Q11	VDDQ	Vss	Vss	Vss	VDDQ	NC	D6	Q6
F	NC	Q12	D12	VDDQ	VDD	Vss	VDD	VDDQ	NC	NC	Q5
G	NC	D13	Q13	VDDQ	VDD	Vss	VDD	VDDQ	NC	NC	D5
н	Doff	VREF	VDDQ	VDDQ	VDD	Vss	VDD	VDDQ	Vddq	VREF	ZQ
J	NC	NC	D14	VDDQ	VDD	Vss	VDD	VDDQ	NC	Q4	D4
K	NC	NC	Q14	VDDQ	VDD	Vss	VDD	VDDQ	NC	D3	Q3
L	NC	Q15	D15	VDDQ	Vss	Vss	Vss	VDDQ	NC	NC	Q2
М	NC	NC	D16	Vss	Vss	Vss	Vss	Vss	NC	Q1	D2
N	NC	D17	Q16	Vss	SA	SA	SA	Vss	NC	NC	D1
Р	NC	NC	Q17	SA	SA	С	SA	SA	NC	D0	Q0
R	TDO	TCK	SA	SA	SA	C	SA	SA	SA	TMS	TDI

Notes: 1. * Checked No Connect(NC) pins are reserved for higher density address, i.e. 10A for 72Mb and 2A for 144Mb. 2. BWo controls write to D0:D8 and BW1 controls write to D9:D17.

PIN NAME

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SYMBOL	PIN NUMBERS	DESCRIPTION	NOTE
K, \overline{K}	6B, 6A	Input Clock	
C, \overline{C}	6P, 6R	Input Clock for Output Data	1
CQ, \overline{CQ}	11A, 1A	Output Echo Clock	
Doff	1H	DLL Disable when low	
SA	3A,9A,4B,8B,5C-7C,5N-7N,4P,5P,7P,8P,3R-5R,7R-9R	Address Inputs	
D0-17	10P,11N,11M,10K,11J,11G,10E,11D,11C,3B,3C,2D, 3F,2G,3J,3L,3M,2N	Data Inputs	
Q0-17	11P,10M,11L,11K,10J,11F,11E,10C,11B,2B,3D,3E, 2F,3G,3K,2L,3N,3P	Data Outputs	
W	4A	Write Control Pin, active when low	
R	8A	Read Control Pin, active when low	
BW ₀ , BW ₁	7B, 5A	Block Write Control Pin, active when low	
VREF	2H,10H	Input Reference Voltage	
ZQ	11H	Output Driver Impedance Control Input	2
VDD	5F,7F,5G,7G,5H,7H,5J,7J,5K,7K	Power Supply (1.8 V)	
VDDQ	4E,8E,4F,8F,4G,8G,3H,4H,8H,9H,4J,8J,4K,8K,4L,8L	Output Power Supply (1.5V or 1.8V)	
Vss	4C,8C,4D-8D,5E-7E,6F,6G,6H,6J,6K,5L-7L,4M-8M,4N,8N	Ground	
TMS	10R	JTAG Test Mode Select	
TDI	11R	JTAG Test Data Input	
TCK	2R	JTAG Test Clock	
TDO	1R	JTAG Test Data Output	
NC	2A,7A,10A,1B,5B,9B,10B,1C,2C,9C,1D,9D,10D,1E,2E,9E,1F,9F, 10F,1G,9G,10G,1J,2J,9J,1K,2K,9J,1L,9L,10L,1M,2M, 9M,1N,9N,10N,1P,2P,9P	No Connect	3

Notes: 1. C, \overline{C} , K or \overline{K} cannot be set to VREF voltage.

2. When ZQ pin is directly connected to VDD output impedance is set to minimum value and it cannot be connected to ground or left unconnected.

3. Not connected to chip pad internally.



PIN CONFIGURATIONS (TOP VIEW) K7R320982C(4Mx9)

	1	2	3	4	5	6	7	8	9	10	11
Α	CQ	NC/SA*	SA	W	NC	K	NC	R	SA	SA	CQ
В	NC	NC	NC	SA	NC	K	BW	SA	NC	NC	Q3
С	NC	NC	NC	Vss	SA	SA	SA	Vss	NC	NC	D3
D	NC	D4	NC	Vss	Vss	Vss	Vss	Vss	NC	NC	NC
E	NC	NC	Q4	VDDQ	Vss	Vss	Vss	VDDQ	NC	D2	Q2
F	NC	NC	NC	VDDQ	VDD	Vss	VDD	VDDQ	NC	NC	NC
G	NC	D5	Q5	VDDQ	VDD	Vss	VDD	VDDQ	NC	NC	NC
н	Doff	VREF	VDDQ	VDDQ	VDD	Vss	VDD	VDDQ	Vddq	VREF	ZQ
J	NC	NC	NC	VDDQ	VDD	Vss	VDD	VDDQ	NC	Q1	D1
K	NC	NC	NC	VDDQ	VDD	Vss	VDD	VDDQ	NC	NC	NC
L	NC	Q6	D6	VDDQ	Vss	Vss	Vss	VDDQ	NC	NC	Q0
М	NC	NC	NC	Vss	Vss	Vss	Vss	Vss	NC	NC	D0
N	NC	D7	NC	Vss	SA	SA	SA	Vss	NC	NC	NC
Р	NC	NC	Q7	SA	SA	С	SA	SA	NC	D8	Q8
R	TDO	TCK	SA	SA	SA	C	SA	SA	SA	TMS	TDI

Notes: 1. * Checked No Connect (NC) pins are reserved for higher density address, i.e. 2A for 72Mb.
2. BW controls write to D0:D8.

PIN NAME

SYMBOL	PIN NUMBERS	DESCRIPTION	NOTE
K, \overline{K}	6B, 6A	Input Clock	
C, \overline{C}	6P, 6R	Input Clock for Output Data	1
CQ, \overline{CQ}	11A, 1A	Output Echo Clock	
Doff	1H	DLL Disable when low	
SA	3A,9A,10A,4B,8B,5C-7C,5N-7N,4P,5P,7P,8P,3R-5R,7R-9R	Address Inputs	
D0-8	11M,11J,10E,11C,2D,2G,3L,2N,10P	Data Inputs	
Q0-8	11L,10J,11E,11B,3E,3G,2L,3P,11P	Data Outputs	
\overline{W}	4A	Write Control Pin, active when low	
R	8A	Read Control Pin, active when low	
BW	7B	Nibble Write Control Pin, active when low	
VREF	2H,10H	Input Reference Voltage	
ZQ	11H	Output Driver Impedance Control Input	2
VDD	5F,7F,5G,7G,5H,7H,5J,7J,5K,7K	Power Supply (1.8 V)	
VDDQ	4E,8E,4F,8F,4G,8G,3H,4H,8H,9H,4J,8J,4K,8K,4L,8L	Output Power Supply (1.5V or 1.8V)	
Vss	4C,8C,4D-8D,5E-7E,6F,6G,6H,6J,6K,5L-7L,4M-8M,4N,8N	Ground	
TMS	10R	JTAG Test Mode Select	
TDI	11R	JTAG Test Data Input	
TCK	2R	JTAG Test Clock	
TDO	1R	JTAG Test Data Output	
NC	2A,7A,5A,1B,2B,3B,5B,9B,10B,1C,2C,3C,9C,10C,1D,3D,9D,10D, 11D,1E,2E,9E,1F,2F,3F,9F,10F,11F,1G,9G,10G,11G,1J,2J,3J,9J 1K,2K,3K,10K,11K,9K,1L,9L,10L,1M,2M,3M,9M,10M,1N,3N,9N 10N,11N,1P,2P,9P	No Connect	3

Notes: 1. C, \overline{C} , K or \overline{K} cannot be set to VREF voltage.

^{3.} Not connected to chip pad internally.



^{2.} When ZQ pin is directly connected to VDD output impedance is set to minimum value and it cannot be connected to ground or left unconnected.

1Mx36 & 2Mx18 & 4Mx9 QDR™ II b2 SRAM

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GENERAL DESCRIPTION

The K7R323682C,K7R321882C and K7R320982C are 37,748,736-bits QDR (Quad Data Rate) Synchronous Pipelined Burst SRAMs. They are organized as 1,048,576 words by 36bits for K7R323682C, 2,097,152 words by 18 bits for K7R321882C and 4,194,304 words by 9bits for K7R320982C.

The QDR operation is possible by supporting DDR read and write operations through separate data output and input ports with the same cycle. Memory bandwidth is maximized as data can be transferred into SRAM on every rising edge of K and \overline{K} , and transferred out of SRAM on every rising edge of C and \overline{C} . And totally independent read and write ports eliminate the need for high speed bus turn around

Address, data inputs, and all control signals are synchronized to the input clock (K or \overline{K}). Normally data outputs are synchronized to output clocks (C and \overline{C}), but when C and \overline{C} are tied high, the data outputs are synchronized to the input clocks (K and \overline{K}). Read data are referenced to echo clock (CQ or \overline{CQ}) outputs. Read address is registered on rising edges of the input K clocks, and write address is registered on rising edges of the input \overline{K} clocks.

Common address bus is used to access address both for read and write operations. The internal burst counter is fixed to 2-bit sequential for both read and write operations. Synchronous pipeline read and early write enable high speed operations. Simple depth expansion is accomplished by using \overline{R} and \overline{W} for port selection. Byte write operation is supported with $\overline{BW_0}$ and $\overline{BW_1}$ ($\overline{BW_2}$ and $\overline{BW_3}$) pins for x18 (x36) device and only \overline{BW} pin for x9 device.

IEEE 1149.1 serial boundary scan (JTAG) simplifies monitoring package pads attachment status with system.

The K7R323682C,K7R321882C and K7R320982C are implemented with SAMSUNG's high performance 6T CMOS technology and is available in 165pin FBGA packages. Multiple power and ground pins minimize ground bounce.

Read Operations

Read cycles are initiated by activating \overline{R} at the rising edge of the positive input clock K. Address is presented and stored in the read address register synchronized with K clock. For 2-bit burst DDR operation, it will access two 36-bit or 18-bit or 9-bit data words with each read command.

The first pipelined data is transferred out of the device triggered by \overline{C} clock following next \overline{K} clock rising edge. Next burst data is triggered by the rising edge of following C clock rising edge. Continuous read operations are initiated with K clock rising edge. And pipelined data are transferred out of device on every rising edge of both C and \overline{C} clocks. In case C and \overline{C} tied to high, output data are triggered by K and \overline{K} instead of C and \overline{C} .

When the \overline{R} is disabled after a read operation, the K7R323682C,K7R321882C and K7R320982C will first complete burst read operation before entering into deselect mode at the next K clock rising edge. Then output drivers disabled automatically to high impedance state.

Write Operations

Write cycles are initiated by activating \overline{W} at the rising edge of the positive input clock K. Address is presented and stored in the write address register synchronized with following \overline{K} clock. For 2-bit burst DDR operation, it will write two 36-bit or 18-bit or 9-bit data words with each write command.

The first "early" data is transferred and registered in to the device synchronous with same K clock rising edge with \overline{W} presented. Next burst data is transferred and registered synchronous with following \overline{K} clock rising edge. Continuous write operations are initiated with K rising edge. And "early write" data is presented to the device on every rising edge of both K and \overline{K} clocks.

When the \overline{W} is disabled, the K7R323682C,K7R321882C and K7R320982C will enter into deselect mode. The device disregards input data presented on the same cycle \overline{W} disabled.

The K7R323682C, K7R321882C and K7R320982C support byte write operations. With activating $\overline{BW_0}$ or $\overline{BW_1}$ ($\overline{BW_2}$ or $\overline{BW_3}$) in write cycle, only one byte of input data is presented. In K7R321882C, $\overline{BW_0}$ controls write operation to D0:D8, $\overline{BW_1}$ controls write operation to D9:D17. And in K7R323682C $\overline{BW_2}$ controls write operation to D18:D26, $\overline{BW_3}$ controls write operation to D27:D35. And in K7R320982C \overline{BW} controls write operation to D0:D8.



$1Mx36 \& 2Mx18 \& 4Mx9 QDR^{TM} II b2 SRAM$

Single Clock Mode

K7R323682C,K7R321882C and K7R320982C can be operated with the single clock pair K and \overline{K} , instead of C or \overline{C} for output clocks. To operate these devices in single clock mode, C and \overline{C} must be tied high during power up and must be maintained high during operation. After power up, this device can't change to or from single clock mode. System flight time and clock skew could not be compensated in this mode.

Depth Expansion

Separate input and output ports enables easy depth expansion. Each port can be selected and deselected independently and read and write operation do not affect each other. Before chip deselected, all read and write pending operations are completed.

Programmable Impedance Output Buffer Operation

The designer can program the SRAM's output buffer impedance by terminating the ZQ pin to Vss through a precision resistor (RQ). The value of RQ (within 15%) is five times the output impedance desired. For example, 250Ω resistor will give an output impedance

Impedance updates occur early in cycles that do not activate the outputs, such as deselect cycles. In all cases impedance updates are transparent to the user and do not produce access time "push-outs" or other anomalous behavior in the SRAM.

To guarantee optimum output driver impedance after power up, the SRAM needs 1024 non-read cycles. 表多地方

Echo clock operation

To assure the output traceability, the SRAM provides the output Echo clock, pair of compliment clock CQ and \overline{CQ} , which are synchronized with internal data output. Echo clocks run free during normal operation.

The Echo clock is triggered by internal output clock signal, and transferred to external through same structures as output driver.

Clock Consideration

K7R323682C,K7R321882C and K7R320982C utilizes internal DLL (Delay-Locked Loops) for maximum output data valid window. It can be placed into a stopped-clock state to minimize power with a modest restart time of 1024 clock cycles. Circuitry automatically resets the DLL when absence of input clock is detected.

Power-Up/Power-Down Supply Voltage Sequencing

The following power-up supply voltage application is recommended: Vss, Vdd, Vref, then Vin. Vdd and Vdd can be applied simultaneously, as long as VDDQ does not exceed VDD by more than 0.5V during power-up. The following power-down supply voltage removal sequence is recommended: VIN, VREF, VDDQ, VDD, VSS. VDD and VDDQ can be removed simultaneously, as long as VDDQ does not exceed VDD by more than 0.5V during power-down.



Detail Specification of Power-Up Sequence in QDRII SRAM

QDRII SRAMs must be powered up and initialized in a predefined manner to prevent undefined operations.

Power-Up Sequence

- 1. Apply power and keep Doff at low state (All other inputs may be undefined)
 - Apply VDD before VDDQ
 - Apply VDDQ before VREF or the same time with VREF
- 2. Just after the stable power and clock (K, \overline{K} , C, \overline{C}), take $\overline{\text{Doff}}$ to be high.
- 3. The additional 1024cycles of clock input is required to lock the DLL after enabling DLL
 - * **Notes**: If you want to tie up the Doff pin to High with unstable clock, then you must stop the clock for a few seconds (Min. 30ns) to reset the DLL after it become a stable clock status.

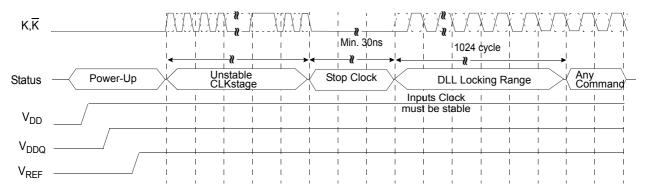
DLL Constraints

Doff

- 1. DLL uses either K or C clock as its synchronizing input, the input should have low phase jitter which is specified as TKC var.
- 2. The lower end of the frequency at which the DLL can operate is 8.4ns.
- 3. If the incoming clock is unstable and the DLL is enabled, then the DLL may lock onto a wrong frequency and this may cause the failure in the initial stage.

Power up & Initialization Sequence (Doff pin controlled) K,K Status Power-Up Unstable CLKstage DLL Locking Range Any Command Inputs Clock must be stable VDD VDD VREF

Power up & Initialization Sequence (Doff pin Fixed high, Clock controlled)



* Notes: When the operating frequency is changed, DLL reset should be required again.

After DLL reset again, the minimum 1024 cycles of clock input is needed to lock the DLL.



TRUTH TABLES

SYNCHRONOUS TRUTH TABLE

K	R W		R W D			Q		
N.	ĸ	VV	D(A0)	D(A1)	Q(A0)	Q(A1)	OPERATION	
Stopped	X	Х	Previous state	Previous state	Previous state	Previous state	Clock Stop	
↑	Н	Н	X	X	High-Z	High-Z	No Operation	
↑	L	Х	x	X	Dou⊤ at C (t+1)	Douт at C(t+2)	Read	
↑	Х	L	Din at K(t)	Din at K(t)	Х	Х	Write	

Notes: 1. X means "Don't Care".

- 2. The rising edge of clock is symbolized by (\uparrow).
- 3. Before enter into clock stop status, all pending read and write operations will be completed.

WRITE TRUTH TABLE(x18)

K	K	BW₀	BW ₁	OPERATION
↑		L	L	WRITE ALL BYTEs (K↑)
	↑	L	L	WRITE ALL BYTEs (K)
↑		L	Н	WRITE BYTE 0 (K↑)
	↑	L	Н	WRITE BYTE 0 (K↑)
↑		Н	L	WRITE BYTE 1 (K1)
	↑	Н	L 3/2 3/2	WRITE BYTE 1 (K↑)
<u></u>		Н	9 9 T	WRITE NOTHING (K1)
	<u></u>	Н	ЭН	WRITE NOTHING (K↑)

Notes: 1. X means "Don't Care".

- 2. All inputs in this table must meet setup and hold time around the rising edge of input clock K or $\overline{\text{K}}$ (\uparrow).
- 3. Assumes a WRITE cycle was initiated.
- 4. This table illustrates operation for x18 devices, x9 device operation is similar except that \overline{BW} controls D0:D8.

WRITE TRUTH TABLE(x36)

K	K	BW ₀	BW ₁	BW ₂	BW ₃	OPERATION
↑		L	L	L	L	WRITE ALL BYTEs (K↑)
	↑	L	L	L	L	WRITE ALL BYTEs (K↑)
↑		L	Н	Н	Н	WRITE BYTE 0 (K↑)
	↑	L	Н	Н	Н	WRITE BYTE 0 (K↑)
↑		Н	L	Н	Н	WRITE BYTE 1 (K↑)
	↑	Н	L	Н	Н	WRITE BYTE 1 (K↑)
↑		Н	Н	L	L	WRITE BYTE 2 and BYTE 3 (K↑)
	↑	Н	Н	L	L	WRITE BYTE 2 and BYTE 3 (\overline{K}^{\uparrow})
↑		Н	Н	Н	Н	WRITE NOTHING (K1)
	↑	Н	Н	Н	Н	WRITE NOTHING (K↑)

Notes: 1. X means "Don't Care".

- 2. All inputs in this table must meet setup and hold time around the rising edge of input clock K or $\overline{\mathsf{K}}$ (\uparrow).
- 3. Assumes a WRITE cycle was initiated.



ABSOLUTE MAXIMUM RATINGS*

PARAMETE	R	SYMBOL	RATING	UNIT
Voltage on VDD Supply Relative to Vss		VDD	-0.5 to 2.9	V
Voltage on VDDQ Supply Relative to Vss		VDDQ	-0.5 to VDD	V
Voltage on Input Pin Relative to Vss		Vin	-0.5 to VDD+0.3	V
Storage Temperature		Тѕтс	-65 to 150	°C
Operating Temperature Commercial / Industrial		Topr	0 to 70 / -40 to 85	°C
Storage Temperature Range Under Bias		TBIAS	-10 to 85	°C

^{*}Note: 1. Stresses greater than those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operating sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

OPERATING CONDITIONS

PARAMETER	SYMBOL	Min	MAX	UNIT
Supply Voltage	Vdd	1.7	1.9	V
Supply Voltage	VDDQ	1.4	1.9	V
Reference Voltage	VREF	0.68	0.95	V

DC ELECTRICAL CHARACTERISTICS

PARAMETER	SYMBOL	TEST CONDITIONS	₹0c 3	MIN	MAX	UNIT	NOTES
Input Leakage Current	lıL	VDD=Max; VIN=Vss to VDDQ	19	-2	+2	μΑ	
Output Leakage Current	lol	Output Disabled,		-2	+2	μА	
		Von-May loux-0mA	-30	-	850		
Operating Current (x36)	Icc	VDD=Max, IOUT=0mA Cycle Time ≥ tкнкн Min	-25	-	800	mA	1,5
		Syste Time E utility Will	-20	-	750		
		Mary Jan Con O	-30	-	800		
Operating Current (x18)	lcc	Vdd=Max, louт=0mA Cycle Time ≥ tкнкн Min.	-25	-	750	mA	1,5
		Syste Time & Wilkin Will.	-20	-	700		
		Ver-May laux-Ora	-30	-	750		
Operating Current (x9)	Icc	VDD=Max, IOUT=0mA Cycle Time ≥ tкнкн Min.	-25	-	700	mA	1,5
		Syste Time 2 utility lyini.	-20	-	650		
		Device decelected louzzomA f=May	-30	-	350		
Standby Current (NOP)	ISB1	Device deselected, IouT=0mA, f=Max, All Inputs≤0.2V or ≥ VDD-0.2V	-25	-	330	mA	1,6
		All illbuts≥0.2V 01 ≥ VDD-0.2V		-	300		
Output High Voltage	Voh1			VDDQ/2-0.12	VDDQ/2+0.12	٧	2,7
Output Low Voltage	Vol1			VDDQ/2-0.12	VDDQ/2+0.12	V	3,7
Output High Voltage	Voh2	Iон=-1.0mA		VDDQ-0.2	VDDQ	V	4
Output Low Voltage	VOL2	IoL=1.0mA		Vss	0.2	V	4
Input Low Voltage	VIL			-0.3	VREF-0.1	V	8,9
Input High Voltage	VIH			VREF+0.1	VDDQ+0.3	V	8,10

Notes: 1. Minimum cycle. IOUT=0mA.

- 2. $|IOH| = (VDDQ/2)/(RQ/5) \pm 15\%$ for $175\Omega \le RQ \le 350\Omega$.
- 3. $|IoL|=(V_{DDQ}/2)/(RQ/5)\pm15\%$ for $175\Omega \le RQ \le 350\Omega$.
- 4. Minimum Impedance Mode when ZQ pin is connected to VDD.
- 5. Operating current is calculated with 50% read cycles and 50% write cycles. 6. Standby Current is only after all pending read and write burst operations are completed.
- 7. Programmable Impedance Mode.
 8. These are DC test criteria. DC design criteria is VREF±50mV. The AC VIH/VIL levels are defined separately for measuring timing parameters.
- 9. VIL (Min.) DC=-0.3V, VIL (Min.) AC=-1.5V(pulse width $\leq 3 ns).$
- 10. VIH (Max)DC=VDDQ+0.3, VIH (Max)AC=VDDQ+0.85V(pulse width \leq 3ns).



^{2.} VDDQ must not exceed VDD during normal operation.

AC ELECTRICAL CHARACTERISTICS

PARAMETER	SYMBOL	MIN	MAX	UNIT	NOTES
Input High Voltage	VIH (AC)	VREF + 0.2	-	V	1,2
Input Low Voltage	VIL (AC)	-	VREF - 0.2	V	1,2

Notes: 1. This condition is for AC function test only, not for AC parameter test.

2. To maintain a valid level, the transition edge of the input must:

- a) Sustain a constant slew rate from the current AC level through the target AC level, VIL(AC) or VIH(AC)
- b) Reach at least the target AC level
- c) After the AC target level is reached, continue to maintain at least the target DC level, VIL(DC) or VIH(DC)

AC TIMING CHARACTERISTICS

DADAMETED	CVMDOL	-3	30	-2	25	-2	20	LINUTO	NOTES
PARAMETER	SYMBOL	MIN	MAX	MIN	MAX	MIN	MAX	UNITS	NOTES
Clock									
Clock Cycle Time (K, \overline{K} , C, $\overline{\overline{C}}$)	tкнкн	3.3	8.40	4.00	8.40	5.00	8.40	ns	
Clock Phase Jitter (K, \overline{K} , C, $\overline{\overline{C}}$)	tKC var		0.20		0.20		0.20	ns	5
Clock High Time (K, K, C, C)	tkhkl	1.32		1.60		2.00		ns	
Clock Low Time (K, \overline{K} , C, $\overline{\overline{C}}$)	tklkh	1.32		1.60		2.00		ns	
Clock to $\overline{\text{Clock}}$ (K $\uparrow \rightarrow \overline{\text{K}}\uparrow$, C $\uparrow \rightarrow \overline{\text{C}}\uparrow$)	tĸн к н	1.49		1.80		2.20		ns	
Clock to data clock $(K\uparrow \to C\uparrow, \overline{K}\uparrow \to \overline{C}\uparrow)$	tкнсн	0.00	1.45	0.00	1.80	0.00	2.30	ns	
DLL Lock Time (K, C)	tKC lock	1024		1024	4,3	1024		cycle	6
K Static to DLL reset	tKC reset	30		30	30	30		ns	
Output Times				3C 75	-00	1		_	_
C, C High to Output Valid	tchqv		0.45	30	0.45		0.45	ns	3
C, C High to Output Hold	tchqx	-0.45		-0.45		-0.45		ns	3
C, C High to Echo Clock Valid	tchcqv		0.45		0.45		0.45	ns	
C, \overline{C} High to Echo Clock Hold	tchcqx	-0.45		-0.45		-0.45		ns	
CQ, CQ High to Output Valid	tcqHqv		0.27		0.30		0.35	ns	7
CQ, CQ High to Output Hold	tсанах	-0.27		-0.30		-0.35		ns	7
C, High to Output High-Z	tchqz		0.45		0.45		0.45	ns	3
C, High to Output Low-Z	tcHQX1	-0.45		-0.45		-0.45		ns	3
Setup Times	-								
Address valid to K rising edge	tavkh	0.3		0.35		0.40		ns	
Control inputs valid to K rising edge	tıvkh	0.3		0.35		0.40		ns	2
Data-in valid to K, K rising edge	tovkh	0.3		0.35		0.40		ns	
Hold Times									
K rising edge to address hold	tkhax	0.3		0.35		0.40		ns	
K rising edge to control inputs hold	tĸнıx	0.3		0.35		0.40		ns	
K, \overline{K} rising edge to data-in hold	tkhdx	0.3		0.35		0.40		ns	

Notes: 1. All address inputs must meet the specified setup and hold times for all latching clock edges.

- 2. Control singles are R, W,BWo,BW1 and BW2, BW3, also for x36
 3. If C,C are tied high, K,K become the references for C,C timing parameters.
- 4. To avoid bus contention, at a given voltage and temperature tCHQX1 is bigger than tCHQZ. The specs as shown do not imply bus contention because tCHQX1 is a MIN parameter that is worst case at totally different test conditions (0°C, 1.9V) than tCHQZ, which is a MAX parameter (worst case at 70°C, 1.7V)
- It is not possible for two SRAMs on the same board to be at such different voltage and temperature. 5. Clock phase jitter is the variance from clock rising edge to the next expected clock rising edge.
- 6. Vdd slew rate must be less than 0.1V DC per 50 ns for DLL lock retention. DLL lock time begins once Vdd and input clock are stable.
- 7. Echo clock is very tightly controlled to data valid/data hold. By design, there is a ± 0.1 ns variation from echo clock to data. The data sheet parameters reflect tester guardbands and test setup variations.



THERMAL RESISTANCE

PRMETER	SYMBOL	Тур	Unit	NOTES
Junction to Ambient	θЈА	20.8	°C/W	
Junction to Case	θјС	2.3	°C/W	
Junction to Pins	θЈВ	4.3	°C/W	

Note: Junction temperature is a function of on-chip power dissipation, package thermal impedance, mounting site temperature and mounting site thermal impedance. TJ=TA + PD x θ JA

PIN CAPACITANCE

PRMETER	SYMBOL	TESTCONDITION	Тур	Max	Unit	NOTES
Address Control Input Capacitance	CIN	VIN=0V	3.5	4	pF	
Input and Output Capacitance	Соит	Vout=0V	4	5	pF	
Clock Capacitance	Cclk	-	3	4	pF	

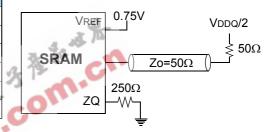
Note: 1. Parameters are tested with RQ=250 Ω and VDDQ=1.5V.

2. Periodically sampled and not 100% tested.

AC TEST CONDITIONS

Parameter	Symbol	Value	Unit
Core Power Supply Voltage	VDD	1.7~1.9	V
Output Power Supply Voltage	VDDQ	1.4~1.9	V
Input High/Low Level	VIH/VIL	1.25/0.25	V
Input Reference Level	VREF	0.75	V
Input Rise/Fall Time	Tr/Tf	0.3/0.3	ns
Output Timing Reference Level		VDDQ/2	V

AC TEST OUTPUT LOAD

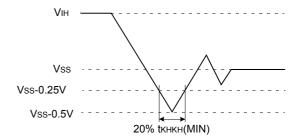


Note: Parameters are tested with RQ=250 Ω

Overershoot Timing

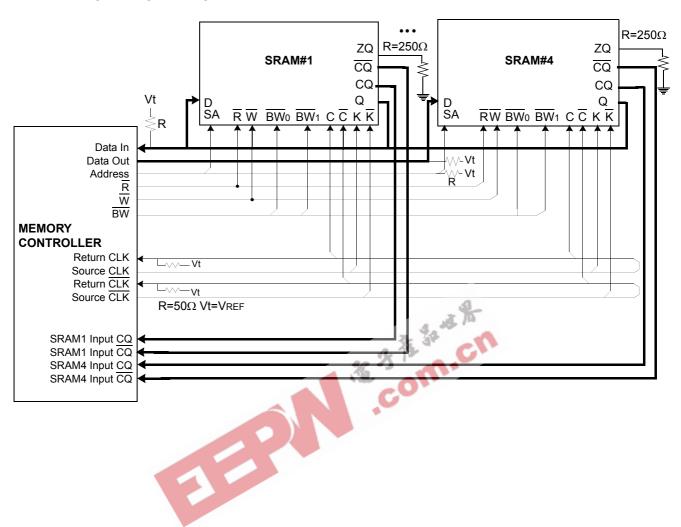


Undershoot Timing



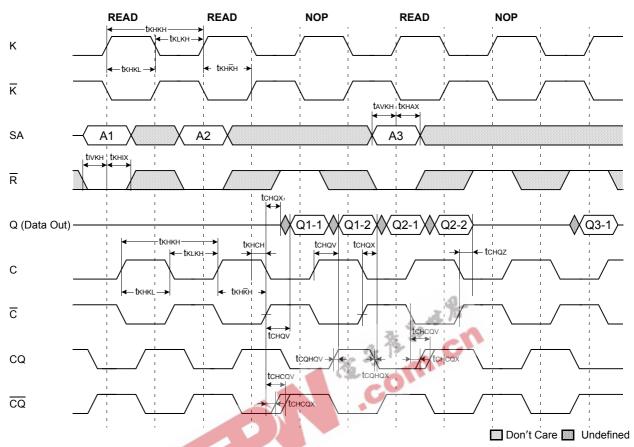
Note: For power-up, ViH \leq VdDQ+0.3V and VdD \leq 1.7V and VdDQ \leq 1.4V $t \leq$ 200ms

APPLICATION INRORMATION





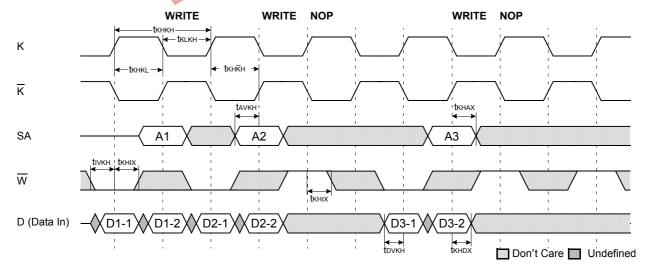
TIMING WAVE FORMS OF READ AND NOP



Note: 1. Q1-1 refers to output from address A1+0, Q1-2 refers to output from address A1+1 i.e. the next internal burst address following A1+0.

2. Outputs are disabled one cycle after a NOP.

TIMING WAVE FORMS OF WRITE AND NOP

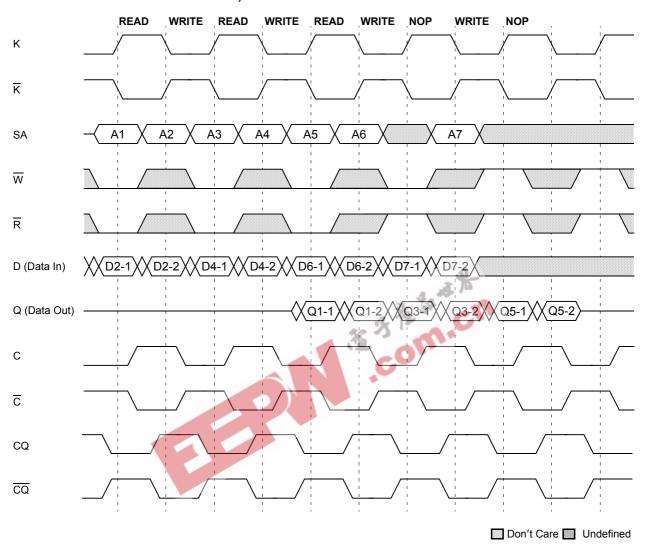


Note: 1.D1-1 refers to input to address A1+0, D1-2 refers to input to address A1+1, i.e the next internal burst address following A1+0.

2. BWx (NWx) assumed active.



TIMING WAVE FORMS OF READ, WRITE AND NOP



Note: 1. If address A1=A2, data Q1-1=D2-1, data Q1-2=D2-2.

Write data is forwarded immediately as read results.

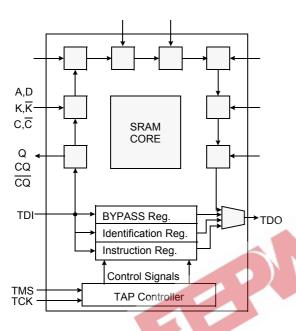
2. BWx (NWx) assumed active.



IEEE 1149.1 TEST ACCESS PORT AND BOUNDARY SCAN-JTAG

This part contains an IEEE standard 1149.1 Compatible Test Access Port (TAP). The package pads are monitored by the Serial Scan circuitry when in test mode. This is to support connectivity testing during manufacturing and system diagnostics. Internal data is not driven out of the SRAM under JTAG control. In conformance with IEEE 1149.1, the SRAM contains a TAP controller, Instruction Register, Bypass Register and ID register. The TAP controller has a standard 16-state machine that resets internally upon power-up, therefore, TRST signal is not required. It is possible to use this device without utilizing the TAP. To disable the TAP controller without interfacing with normal operation of the SRAM, TCK must be tied to Vss to preclude mid level input. TMS and TDI are designed so an undriven input will produce a response identical to the application of a logic 1, and may be left unconnected. But they may also be tied to VDD through a resistor. TDO should be left unconnected.

JTAG Block Diagram



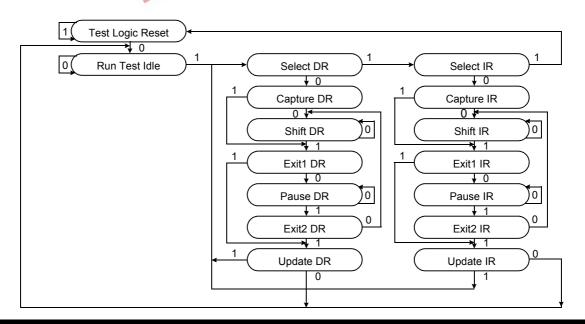
JTAG Instruction Coding

IR2	IR1	IR0	Instruction	TDO Output	Notes
0	0	0	EXTEST	Boundary Scan Register	1
0	0	1	IDCODE	Identification Register	3
0	1	0	SAMPLE-Z	Boundary Scan Register	2
0	1	1	RESERVED	Do Not Use	6
1	0	0	SAMPLE	Boundary Scan Register	5
1	0	1	RESERVED	Do Not Use	6
1	1	0	RESERVED	Do Not Use	6
1	1	1	BYPASS	Bypass Register	4

NOTE:

- Places DQs in Hi-Z in order to sample all input data regardless of other SRAM inputs. This instruction is not IEEE 1149.1 compliant.
- Places DQs in Hi-Z in order to sample all input data regardless of other SRAM inputs.
- TDI is sampled as an input to the first ID register to allow for the serial shift of the external TDI data.
- 4. Bypass register is initiated to Vss when BYPASS instruction is invoked. The Bypass Register also holds serially loaded TDI when exiting the Shift DR states.
- 5. SAMPLE instruction dose not places DQs in Hi-Z.
- 6. This instruction is reserved for future use.

TAP Controller State Diagram





SCAN REGISTER DEFINITION

Part	Instruction Register	Bypass Register	ID Register	Boundary Scan
1Mx36	3 bits	1 bit	32 bits	109 bits
2Mx18	3 bits	1 bit	32 bits	109 bits
4Mx9	3 bits	1 bit	32 bits	109 bits

ID REGISTER DEFINITION

Part	Revision Number (31:29)	Part Configuration (28:12)	Samsung JEDEC Code (11: 1)	Start Bit(0)
1Mx36	000	00def0wx0t0q0b0s0	00011001110	1
2Mx18	000	00def0wx0t0q0b0s0	00011001110	1
4Mx9	000	00def0wx0t0q0b0s0	00011001110	1

Note: Part Configuration

/def=010 for 36Mb, /wx=11 for x36, 10 for x18, 00 for x9.

/t=1 for DLL Ver., 0 for non-DLL Ver. /q=1 for QDR, 0 for DDR /b=1 for 4Bit Burst, 0 for 2Bit Burst /s=1 for Separate I/O, 0 for Common I/O

ORDER

PIN ID

BOUNDARY SCAN EXIT ORDER

ORDER PIN ID 1 6R 2 6P 3 6N 4 7P 5 7N 6 7R 7 8R 8 8P 9 9R 10 11P 11 10P 12 10N 13 9P 14 10M 15 11N 16 9M 17 9N 18 11L 19 11M 20 9L 21 10L 22 11K 23 10K 24 9J 25 9K 26 10J 27 11J 28 11H 29 10G 30 9G 31 11F 32 11G 33 9F 34<	BOONBAILL	SOAR EXIT OF
2 6P 3 6N 4 7P 5 7N 6 7R 7 8R 8 8P 9 9R 10 11P 11 10P 11 10P 12 10N 13 9P 14 10M 15 11N 16 9M 17 9N 18 11L 19 11M 20 9L 21 10L 22 11K 23 10K 24 9J 25 9K 26 10J 27 11J 28 11H 29 10G 30 9G 31 11F 32 11G 33 9F 34 10F 35 11E	ORDER	PIN ID
3 6N 4 7P 5 7N 6 7R 7 8R 8 8P 9 9R 10 11P 11 10P 11 10P 12 10N 13 9P 14 10M 15 11N 16 9M 17 9N 18 11L 19 11M 20 9L 21 10L 22 11K 23 10K 24 9J 25 9K 26 10J 27 11J 28 11H 29 10G 30 9G 31 11F 32 11G 33 9F 34 10F 35 11E	1	6R
4 7P 5 7N 6 7R 7 8R 8 8P 9 9R 10 11P 11 10P 11 10P 12 10N 13 9P 14 10M 15 11N 16 9M 17 9N 18 11L 19 11M 20 9L 21 10L 22 11K 23 10K 24 9J 25 9K 26 10J 27 11J 28 11H 29 10G 30 9G 31 11F 32 11G 33 9F 34 10F 35 11E	2	6P
5 7N 6 7R 7 8R 8R 8 8P 9 9R 10 11P 11 10P 11 10P 12 10N 13 9P 14 10M 15 11N 16 9M 17 9N 18 11L 19 11M 20 9L 21 10L 22 11K 23 10K 24 9J 25 9K 26 10J 27 11J 28 11H 29 10G 30 9G 31 11F 32 11G 33 9F 34 10F 35 11E	3	6N
6 7R 7 8R 8 8P 9 9R 10 11P 11 10P 11 10P 12 10N 13 9P 14 10M 15 11N 16 9M 17 9N 18 11L 19 11M 20 9L 21 10L 22 11K 23 10K 24 9J 25 9K 26 10J 27 11J 28 11H 29 10G 30 9G 31 11F 32 11G 33 9F 34 10F 35 11E	4	7P
7 8R 8 8P 9 9R 10 11P 11 10P 11 10P 12 10N 13 9P 14 10M 15 11N 16 9M 17 9N 18 11L 19 11M 20 9L 21 10L 22 11K 23 10K 24 9J 25 9K 26 10J 27 11J 28 11H 29 10G 30 9G 31 11F 32 11G 33 9F 34 10F 35 11E	5	7N
8 8P 9 9R 10 11P 11 10P 12 10N 13 9P 14 10M 15 11N 16 9M 17 9N 18 11L 19 11M 20 9L 21 10L 22 11K 23 10K 24 9J 25 9K 26 10J 27 11J 28 11H 29 10G 30 9G 31 11F 32 11G 33 9F 34 10F 35 11E	6	7R
9 9R 10 11P 11 10P 11 10N 12 10N 13 9P 14 10M 15 11N 16 9M 17 9N 18 11L 19 11M 20 9L 21 10L 22 11K 23 10K 24 9J 25 9K 26 10J 27 11J 28 11H 29 10G 30 9G 31 11F 32 11G 33 9F 34 10F 35 11E	7	8R
10 11P 11 10P 11 10P 12 10N 13 9P 14 10M 15 11N 16 9M 17 9N 18 11L 19 11M 20 9L 21 10L 22 11K 23 10K 24 9J 25 9K 26 10J 27 11J 28 11H 29 10G 30 9G 31 11F 32 11G 33 9F 34 10F 35 11E	8	8P
11 10P 12 10N 13 9P 14 10M 15 11N 16 9M 17 9N 18 11L 19 11M 20 9L 21 10L 22 11K 23 10K 24 9J 25 9K 26 10J 27 11J 28 11H 29 10G 30 9G 31 11F 32 11G 33 9F 34 10F 35 11E	9	9R
12 10N 13 9P 14 10M 15 11N 16 9M 17 9N 18 11L 19 11M 20 9L 21 10L 22 11K 23 10K 24 9J 25 9K 26 10J 27 11J 28 11H 29 10G 30 9G 31 11F 32 11G 33 9F 34 10F 35 11E	10	11P
13 9P 14 10M 15 11N 16 9M 17 9N 18 11L 19 11M 20 9L 21 10L 22 11K 23 10K 24 9J 25 9K 26 10J 27 11J 28 11H 29 10G 30 9G 31 11F 32 11G 33 9F 34 10F 35 11E	11	10P
14 10M 15 11N 16 9M 17 9N 18 11L 19 11M 20 9L 21 10L 22 11K 23 10K 24 9J 25 9K 26 10J 27 11J 28 11H 29 10G 30 9G 31 11F 32 11G 33 9F 34 10F 35 11E	12	10N
15 11N 16 9M 17 9N 18 11L 19 11M 20 9L 21 10L 22 11K 23 10K 24 9J 25 9K 26 10J 27 11J 28 11H 29 10G 30 9G 31 11F 32 11G 33 9F 34 10F 35 11E	13	9P
16 9M 17 9N 18 11L 19 11M 20 9L 21 10L 22 11K 23 10K 24 9J 25 9K 26 10J 27 11J 28 11H 29 10G 30 9G 31 11F 32 11G 33 9F 34 10F 35 11E	14	10M
17 9N 18 11L 19 11M 20 9L 21 10L 22 11K 23 10K 24 9J 25 9K 26 10J 27 11J 28 11H 29 10G 30 9G 31 11F 32 11G 33 9F 34 10F 35 11E	15	11N
18 11L 19 11M 20 9L 21 10L 22 11K 23 10K 24 9J 25 9K 26 10J 27 11J 28 11H 29 10G 30 9G 31 11F 32 11G 33 9F 34 10F 35 11E		9M
19 11M 20 9L 21 10L 22 11K 23 10K 24 9J 25 9K 26 10J 27 11J 28 11H 29 10G 30 9G 31 11F 32 11G 33 9F 34 10F 35 11E	17	9N
20 9L 21 10L 22 11K 23 10K 24 9J 25 9K 26 10J 27 11J 28 11H 29 10G 30 9G 31 11F 32 11G 33 9F 34 10F 35 11E	18	11L
21 10L 22 11K 23 10K 24 9J 25 9K 26 10J 27 11J 28 11H 29 10G 30 9G 31 11F 32 11G 33 9F 34 10F 35 11E	19	11M
22 11K 23 10K 24 9J 25 9K 26 10J 27 11J 28 11H 29 10G 30 9G 31 11F 32 11G 33 9F 34 10F 35 11E	20	9L
23 10K 24 9J 25 9K 26 10J 27 11J 28 11H 29 10G 30 9G 31 11F 32 11G 33 9F 34 10F 35 11E	21	10L
24 9J 25 9K 26 10J 27 11J 28 11H 29 10G 30 9G 31 11F 32 11G 33 9F 34 10F 35 11E	22	11K
25 9K 26 10J 27 11J 28 11H 29 10G 30 9G 31 11F 32 11G 33 9F 34 10F 35 11E	23	10K
26 10J 27 11J 28 11H 29 10G 30 9G 31 11F 32 11G 33 9F 34 10F 35 11E	24	9J
27 11J 28 11H 29 10G 30 9G 31 11F 32 11G 33 9F 34 10F 35 11E	25	9K
28 11H 29 10G 30 9G 31 11F 32 11G 33 9F 34 10F 35 11E	26	10J
29 10G 30 9G 31 11F 32 11G 33 9F 34 10F 35 11E	27	11J
30 9G 31 11F 32 11G 33 9F 34 10F 35 11E	28	11H
31 11F 32 11G 33 9F 34 10F 35 11E	29	10G
32 11G 33 9F 34 10F 35 11E	30	9G
33 9F 34 10F 35 11E	31	11F
34 10F 35 11E	32	11G
35 11E	33	9F
	34	10F
36 10E	35	11E
	36	10E

URDER	PIN ID
37	10D
38	9E
39	10C
40	11D
41	9C
42	9D
43	11B
44	11C
45	9B
46	10B
47	11A
48	10A
49	9A
50	8B
51	7C
52	6C
53	8A
54	7A
55	7B
56	6B
57	6A
58	5B
59	5A
60	4A
61	5C
62	4B
63	3A
64	2A
65	1A
66	2B
67	3B
68	1C
69	1B
70	3D
71	3C
72	1D

73 2C 74 3E 75 2D 76 2E 77 1E 78 2F 79 3F 80 1G 81 1F 82 3G 83 2G 84 1H 85 1J 86 2J 87 3K 88 3J 89 2K 90 1K 91 2L 92 3L 93 1M 94 1L 95 3N 96 3M 97 1N 98 2M 99 3P 100 2N 101 2P 102 1P 103 3R 104 4R 105 4P 106 5P 107	ORDER	PIN ID		
75 2D 76 2E 77 1E 78 2F 79 3F 80 1G 81 1F 82 3G 83 2G 84 1H 85 1J 86 2J 87 3K 88 3J 89 2K 90 1K 91 2L 92 3L 92 3L 93 1M 94 1L 95 3N 96 3M 97 1N 98 2M 99 3P 100 2N 101 2P 102 1P 103 3R 104 4R 105 4P 106 5P 107 5N 108 5R	73	2C		
76		3E		
76	10	2D		
78	76	2E		
79 3F 80 1G 81 1F 82 3G 83 2G 84 1H 85 1J 86 2J 87 3K 88 3J 89 2K 90 1K 91 2L 92 3L 93 1M 94 1L 95 3N 96 3M 97 1N 98 2M 99 3P 100 2N 101 2P 102 1P 103 3R 104 4R 105 4P 106 5P 107 5N 108 5R	7 7	1E		
80 1G 81 1F 82 3G 83 2G 84 1H 85 1J 86 2J 87 3K 88 3J 89 2K 90 1K 91 2L 92 3L 93 1M 94 1L 95 3N 96 3M 97 1N 98 2M 99 3P 100 2N 101 2P 102 1P 103 3R 104 4R 105 4P 106 5P 107 5N 108 5R	78	2F		
81 1F 82 3G 83 2G 84 1H 85 1J 86 2J 87 3K 88 3J 89 2K 90 1K 91 2L 92 3L 93 1M 94 1L 95 3N 96 3M 97 1N 98 2M 99 3P 100 2N 101 2P 102 1P 103 3R 104 4R 105 4P 106 5P 107 5N 108 5R	79	3F		
82 3G 83 2G 84 1H 85 1J 86 2J 87 3K 88 3J 89 2K 90 1K 91 2L 92 3L 92 3L 93 1M 94 1L 95 3N 96 3M 97 1N 98 2M 99 3P 100 2N 101 2P 102 1P 103 3R 104 4R 105 4P 106 5P 107 5N 108 5R	80	1G		
83 2G 84 1H 85 1J 86 2J 87 3K 88 3J 89 2K 90 1K 91 2L 92 3L 93 1M 94 1L 95 3N 96 3M 97 1N 98 2M 99 3P 100 2N 101 2P 102 1P 103 3R 104 4R 105 4P 106 5P 107 5N 108 5R	81	1F		
84 1H 85 1J 86 2J 87 3K 88 3J 89 2K 90 1K 91 2L 92 3L 93 1M 94 1L 95 3N 96 3M 97 1N 98 2M 99 3P 100 2N 101 2P 102 1P 103 3R 104 4R 105 4P 106 5P 107 5N 108 5R	82	3G		
85 1J 86 2J 87 3K 88 3J 89 2K 90 1K 91 2L 92 3L 93 1M 94 1L 95 3N 96 3M 97 1N 98 2M 99 3P 100 2N 101 2P 102 1P 103 3R 104 4R 105 4P 106 5P 107 5N 108 5R	83	2G		
86 2J 87 3K 88 3J 89 2K 90 1K 91 2L 92 3L 93 1M 94 1L 95 3N 96 3M 97 1N 98 2M 99 3P 100 2N 101 2P 102 1P 103 3R 104 4R 105 4P 106 5P 107 5N 108 5R	84	1H		
87 3K 88 3J 89 2K 90 1K 91 2L 92 3L 93 1M 94 1L 95 3N 96 3M 97 1N 98 2M 99 3P 100 2N 101 2P 102 1P 103 3R 104 4R 105 4P 106 5P 107 5N 108 5R	85	1J		
88 3J 89 2K 90 1K 91 2L 92 3L 93 1M 94 1L 95 3N 96 3M 97 1N 98 2M 99 3P 100 2N 101 2P 102 1P 103 3R 104 4R 105 4P 106 5P 107 5N 108 5R	86	2J		
89 2K 90 1K 91 2L 92 3L 93 1M 94 1L 95 3N 96 3M 97 1N 98 2M 99 3P 100 2N 101 2P 102 1P 103 3R 104 4R 105 4P 106 5P 107 5N 108 5R	87	3K		
90 1K 91 2L 92 3L 93 1M 94 1L 95 3N 96 3M 97 1N 98 2M 99 3P 100 2N 101 2P 102 1P 103 3R 104 4R 105 4P 106 5P 107 5N 108 5R	88	3J		
91 2L 92 3L 93 1M 94 1L 95 3N 96 3M 97 1N 98 2M 99 3P 100 2N 101 2P 102 1P 103 3R 104 4R 105 4P 106 5P 107 5N 108 5R	89	2K		
92 3L 93 1M 94 1L 95 3N 96 3M 97 1N 98 2M 99 3P 100 2N 101 2P 102 1P 103 3R 104 4R 105 4P 106 5P 107 5N 108 5R	90	1K		
93 1M 94 1L 95 3N 96 3M 97 1N 98 2M 99 3P 100 2N 101 2P 102 1P 103 3R 104 4R 105 4P 106 5P 107 5N 108 5R	91	2L		
94 1L 95 3N 96 3M 97 1N 98 2M 99 3P 100 2N 101 2P 102 1P 103 3R 104 4R 105 4P 106 5P 107 5N 108 5R	92	3L		
95 3N 96 3M 97 1N 98 2M 99 3P 100 2N 101 2P 102 1P 103 3R 104 4R 105 4P 106 5P 107 5N 108 5R	93	1M		
96 3M 97 1N 98 2M 99 3P 100 2N 101 2P 102 1P 103 3R 104 4R 105 4P 106 5P 107 5N 108 5R	94	1L		
97 1N 98 2M 99 3P 100 2N 101 2P 102 1P 103 3R 104 4R 105 4P 106 5P 107 5N 108 5R	95	3N		
98 2M 99 3P 100 2N 101 2P 102 1P 103 3R 104 4R 105 4P 106 5P 107 5N 108 5R	96	3M		
99 3P 100 2N 101 2P 102 1P 103 3R 104 4R 105 4P 106 5P 107 5N 108 5R	97	1N		
100 2N 101 2P 102 1P 103 3R 104 4R 105 4P 106 5P 107 5N 108 5R	98	2M		
101 2P 102 1P 103 3R 104 4R 105 4P 106 5P 107 5N 108 5R	99	3P		
102 1P 103 3R 104 4R 105 4P 106 5P 107 5N 108 5R	100	2N		
103 3R 104 4R 105 4P 106 5P 107 5N 108 5R	101	2P		
104 4R 105 4P 106 5P 107 5N 108 5R	102	1P		
105 4P 106 5P 107 5N 108 5R	103	3R		
106 5P 107 5N 108 5R	104	4R		
107 5N 108 5R	105	4P		
108 5R	106	5P		
	107	5N		
109 Internal	108	5R		
	109	Internal		

Note: 1. NC pins are read as "X" (i.e. don't care.)



JTAG DC OPERATING CONDITIONS

Parameter	Symbol	Min	Тур	Max	Unit	Note
Power Supply Voltage	VDD	1.7	1.8	1.9	V	
Input High Level	VIH	1.3	-	VDD+0.3	V	
Input Low Level	VIL	-0.3	-	0.5	V	
Output High Voltage(IoH=-2mA)	Vон	1.4	-	VDD	V	
Output Low Voltage(IoL=2mA)	Vol	Vss	1	0.4	V	

Note: 1. The input level of SRAM pin is to follow the SRAM DC specification.

JTAG AC TEST CONDITIONS

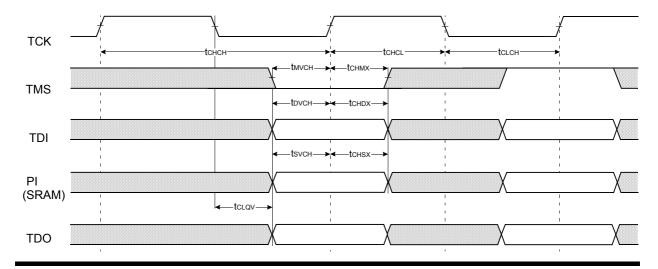
Parameter	Symbol	Min	Unit	Note
Input High/Low Level	VIH/VIL	1.8/0.0	V	
Input Rise/Fall Time	TR/TF	1.0/1.0	ns	
Input and Output Timing Reference Level		0.9	V	1

Note: 1. See SRAM AC test output load on page 11.

JTAG AC Characteristics

JTAG AC Characteristics			4. 4. 6.		
Parameter	Symbol	Min	Max	Unit	Note
TCK Cycle Time	tснсн	50	-0.0	ns	
TCK High Pulse Width	tchcL	20		ns	
TCK Low Pulse Width	tclch	20	-	ns	
TMS Input Setup Time	tmvch	5	-	ns	
TMS Input Hold Time	tchmx	5	-	ns	
TDI Input Setup Time	tdvch	5	-	ns	
TDI Input Hold Time	tcHDX	5	-	ns	
SRAM Input Setup Time	tsvcн	5	-	ns	
SRAM Input Hold Time	tchsx	5	-	ns	
Clock Low to Output Valid	tclqv	0	10	ns	

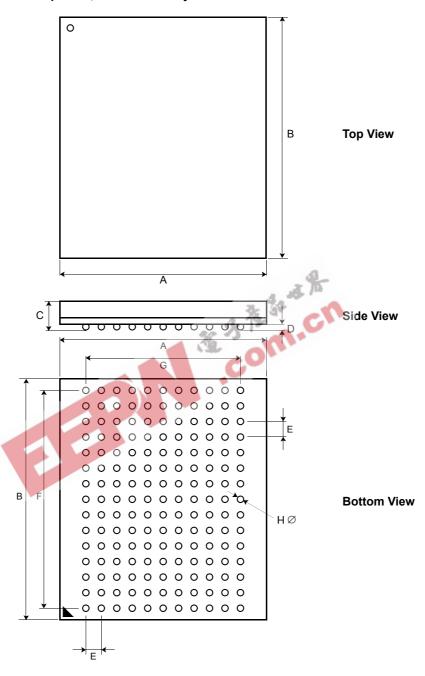
JTAG TIMING DIAGRAM





165 FBGA PACKAGE DIMENSIONS (Lead & Lead-Free)

15mm x 17mm Body, 1.0mm Bump Pitch, 11x15 Ball Array



Symbol	Value	Units	Note	Symbol	Value	Units	Note
Α	15 ± 0.1	mm		E	1.0	mm	
В	17 ± 0.1	mm		F	14.0	mm	
С	1.3 ± 0.1	mm		G	10.0	mm	
D	0.35 ± 0.05	mm		Н	0.5 ± 0.05	mm	

